SAMYANG ELECTRONICS

(SINGLE CHIP) SR520 --- SR5200

SCHOTTKY BARRIER RECTIFIER

VOLTAGE RANGE: 20 --- 200 V CURRENT: 5.0A

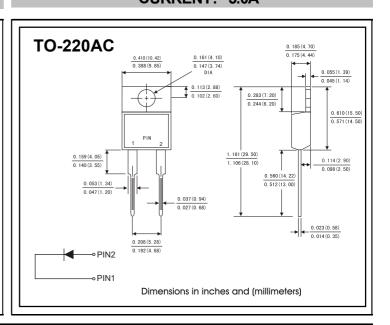
FEATURES

- Metal-semiconductor junction with guard ring

- High surge capability
- For use in low voltage, high frequency inverters free wheeling, and polarity protection applications

MECHANICAL DATA

- ♦ Weight: 0.08 ounces, 2.24 grams



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		Symbols	SR 520	SR 530	SR 540	SR 550	SR 560	SR 580	SR 5100	SR 5150	SR 5200	Units
Maximum repetitive peak reverse voltage		Vrrm	20	30	40	50	60	80	100	150	200	Volts
Maximum RMS voltage		VRMS	14	21	28	35	42	57	71	105	140	Volts
Maximum DC blocking voltage		VDC	20	30	40	50	60	80	100	150	200	Volts
Maximum average forward rectified current 0.375"(9.5mm) lead length(see fig.1)		I(AV)	5.0									Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated T _L)		İfsm	150.0									Amps
Maximum instantaneous forward voltage at 5.0 A(Note 1)		VF	0.55			(0.70	0.85		0.90	0. 95	Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	T _A = 25°C	la la	0.2									
	T _A = 100°C	IR	50 25							mA		
Typical junction capacitance(Note 3)		Cı	500 400							Р F		
Typical thermal resistance (Note 2)		R⊕JA R⊕JL	25.0 8.0									°C/W
Operating junction temperature range		TJ	-65 to+150									C
Storage temperature range		Tstg	-65 to+150									Ç

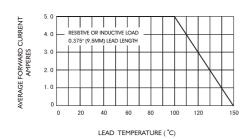
NOTE: 1. Pulse test:300us pulse width,1% duty cycle.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to ambient

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FIG.1-FORWARD CURRENT DERATING CURVE



FORWARD SURGE CURRENT

FIG.2-MAXIMUM NON-REPETITIVE PEAK

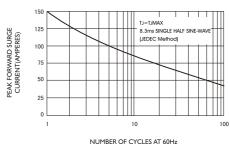


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

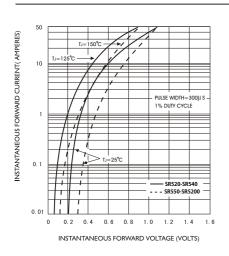


FIG.4-TYPICAL REVERSE CHARACTERISTICS

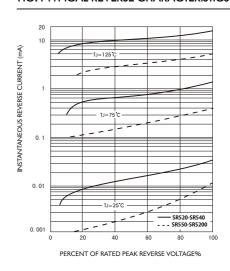


FIG.5-TYPICAL JUNCTION CAPACITANCE

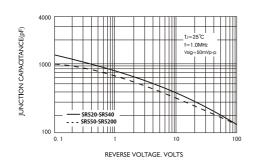
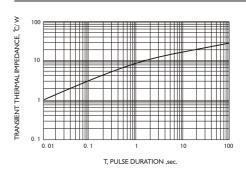


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE



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